

technology

STEREO 2.1W Non-Clip DIGITAL AUDIO POWER AMPLIFIER

Overview

HT2144 is a digital audio power amplifier IC with maximum output of 2.1W (RL=4 Ω)×2ch.

HT2144 has a "Pure Pulse Direct Speaker Drive Circuit" which directly drives speakers while reducing distortion of pulse output signal and reducing noise on the signal, and realizes the highest standard low distortion rate characteristics and low noise characteristics among digital amplifier ICs for mobile use.

In addition, circuit design with fewer external parts can be made depend on the condition of use because corresponds to filter less.

The HT2144 features Heroic original non-clip output control function which detects output signal clip due to the over level input signal and suppress the output signal clip automatically. Also the non-clip output control function can adapt the output clip caused by power supply voltage down with battery. This is the difference from the traditional AGC (Auto Gain Control) or ALC (Auto Level Control) circuit. Attack time and release time can be freely set by external resistances or capacitances.

The independent power-down function for L channel and R channel minimizes consumption current at standby. As for protection function, overcurrent protection function for speaker output terminal, overtemperatue protection function for inside of the device, and low supply voltage malfunction preventing function are prepared.

◆Electrical Characteristic

• Absolute Maximum Ratings

Item	Symbol	Min.	Max.	Unit
Power supply terminal (PVDD) Voltage Range	V _{DDP}	-0.3	6.0	V
Power supply terminal (AVDD) Voltage Range	V _{DDP}	-0.3	6.0	V
Input terminal Voltage Range (Analog input terminals: INL+,INL-,INR+,INR-)	V _{IN}	Vss-0.6	V _{DDA} +0.6	V
Input terminal Voltage Range (Input terminals except the above-mentioned)	V _{IN}	Vss-0.3	V _{DDA} +0.3	V
Allowable dissipation (20QFN,Ta=25°C)	P _{D25}		1.56	W
Allowable dissipation (20QFN,Ta=85°C)	P _{D85}		0.62	W
Allowable dissipation (20QFN,Ta=25°C)	P _{D25}		3.63	W
Allowable dissipation (20QFN,Ta=85°C)	P _{D85}		1.45	W
Junction Temperature	T _{JMAX}		150	°C
Storage Temperature	T _{STG}	-50	125	°C

Note) Absolute Maximum Ratings is values which must not be exceeded to guarantee device reliability and life, and when using a device in excess even a moment, it may immediately cause damage to device or may significantly deteriorate its reliability With a system of which a voltage at an input pin might exceed a supply voltage of VDDA/GND, use an external diode to assure that the voltage does not exceed the absolute maximum rating.

*1: $\theta_{ja}=50.0^{\circ}$ C/W, conditions: HT2144 evaluation board (4 layers), dead calm

*2: $\theta_{ja}=64.0^{\circ}$ C/W, conditions: HT2144 evaluation board (2 layers, without through-hole), dead calm

*3: θja=27.5°C/W, conditions: 4 layers, through-hole, copper foil 65μm, dead calm

• Recommended Operating Condition

Item	Symbol	Min.	Тур.	Max.	Unit
Power Supply Voltage(PVDD)	V _{DDP}	3.5	5	6	V
Power Supply Voltage(AVDD)	V _{DDP}	3.5	5	6	V
Operating Ambient Temperature	Та	-40	25	85	°C
Speaker Impedance (4.5V < PVDD)	R _L	4			Ω
Speaker Impedance $(3.5V \le PVDD \le 4.5V)$	R _L	8			Ω

Note) Do not use under a condition other than the recommended operating conditions.

 $PVDD \ge AVDD$ (contain power supply start up) must be met.

The rising time of PVDD and AVDD should be more than $1\mu\mbox{ s}$.



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• DC Characteristics (VSS=0V, VDDP= VDDA =3.5V to 5.25V, Ta=-40°C to 85°C, unless otherwise specified)

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit
AVDD power supply start-up threshold voltage	V _{UVLH}			2.2		V
AVDD power supply shut-down threshold voltage	V _{UVLL}			2.0		V
/SDL, /SDR, G0 terminal H level input voltage	V _{IH}		1.35			V
/SDL, /SDR, G0 terminal L level input voltage	V _{IL}				0.35	V
AVDD consumption current	I _{DD}	V _{DDA} =3.6v,no load		6.0		mA
PVDD consumption current	I _{DD}	V _{DDA} =3.6v,no load,		2.0		mA
		no signal input				
Consumption current in	I _{PD}	/SDL=/SDR=V _{SS}		0.1		uA
power-down mode AV DD + PV DD		T _a =25℃				

• AC characteristics (Vss=0V, Vddp= Vdda=3.5V to 5.25V, Ta=-40°C to 85°C, unless otherwise specified)

Item	Symbol	Conditions	Min	Тур	Max	Unit
Start-up time	T _{STUP}			3.5		ms
Input cut-off frequency	fc	C _{IN} =0.1uF,Av=18dB		57		Hz
Attack time	T _{AT}	V _{DDA} =3.6v,g=10dB,Cex=1uF,Rex=1MΩ		10		ms
Release time	T _{RL}	V _{DDA} =3.6v,g=10dB,Cex=1uF,Rex=1MΩ		0.8		S
Carrier clock frequency	f _{PWM}			1.0		MHz

• Analog Characteristics

(VSS=0V, VDDP= VDDA =3.6V, RL=8Ω, Ta=25°C, Non-Clip function=OFF, no snubber circuit, no schottky barrier diode,unless otherwise specified)

Item	Symbol	Conditions	Min	Тур	Max	Unit
Maximum output	Ро	$R_L=4\Omega$,		2.1		W
		f=1kHz,THD+N=10%,				
		$V_{DDP}=V_{DDA}=5V$				
		$R_L=8\Omega$,		0.75		W
		f=1kHz,THD+N=10%				
Voltage Gain	Av	G0=L		12		dB
		G0=H		18		dB
Total Harmonic Distortion Rate (BW:20kHz)	THD+N	R _L =8Ω, Po=0.4W, f=1kHz		0.03		%
Residual Noise (A-Filter)	N	Av=12dB		40		uV _{rms}
Signal /Noise Ratio (BW:20kHz A-Filter)	SNR	Av=12dB		95		dB
Channel Separation Ratio	CS	1kHz		95		dB
Power supply rejection ratio	PSRR	217Hz (to P _{VDD})		-85		dB
Maximum Efficiency	η	$R_L=8\Omega$, Po=600mW		84		%
		$R_L=8\Omega$, Po=100mW		78		%



echnology		Nov. 2008		HT2144	Product	Brief	V2.0	
Output offset voltage	Vo			±20		mV		
Frequency characteristics	f _{RES}	C_{IN} =0.1µF, f=100Hz to 20kHz	-3	-	1	dB		
Non-Clip maximum attenuation gain	Aa			-10		dB		

Note) All the values of analog characteristics were obtained by using our evaluation circumstance.

Depending upon parts and pattern layout to use, characteristics may be changed.

 8Ω or 4Ω resistor and 30μ H coil are used as an output load in order to obtain various digital amplifier characteristics.

Terminal configuration





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<20-pin TSSOP Top View>

Application circuit examples

- WLCSP16
- Snubber circuit and schottky barrier diode are unnecessary $(3.5V \le PVDD \le 4.5V)$





• Snubber circuit and schottky barrier diode are necessary (4.5V < PVDD)



When the IC is used at more than 4.5V power supply, use it with an additional capacitor of 10μ F or over between PVDD and GND.

Place a bypass capacitor as close as possible to each power supply pin of the IC.

- QFN20/TSSOP20
- Snubber circuit and schottky barrier diode are unnecessary $(3.5V \le PVDD \le 4.5V)$





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• Snubber circuit and schottky barrier diode are necessary (4.5V < PVDD)



When the IC is used at more than 4.5V power supply, use it with an additional capacitor of 10μ F or over between PVDD and GND.

Place a bypass capacitor as close as possible to each power supply pin of the IC.

Physical Dimensions

QFNWB4×4-20L(P0.50T0.75/0.85) PACKAGE OUTLINE DIMENSIONS





Side View

Cumula al	Dimensions I	n Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
A	0.700/0.800	0.800/0.900	0.028/0.031	0.031/0.035
A1	0.000	0.050	0.000	0.002
A3	0.203	REF.	0.008	BREF.
D	3.900	4.100	0.154	0.161
E	3.900	4.100	0.154	0.161
D1	1.900	2.100	0.075	0.083
E1	1.900	2.100	0.075	0.083
k	0.200	MIN.	0.00	8MIN.
b	0.180	0.300	0.007	0.012
е	0.500	TYP.	0.020	TYP.
L	0.300	0.500	0.012	0.020





TSSOP20/PP PACKAGE OUTLINE DIMENSIONS

G	Dimensions In	n Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
D	6.400	6.600	0.252	0.259
Dl	4.100	4.300	0.165	0.169
E	4.300	4.500	0.169	0.177
ь	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
El	6.250	6.550	0.246	0.258
E2	2.900	3.100	0.114	0.122
A		1.100		0.043
A2	0.800	1.000	0.031	0.039
A1	0.020	0.150	0.001	0.006
e	0.65 (BSC)	0.026	(BSC)
L	0.500	0.700	0.02	0.028
н	0.25(ΓYP)	0.01(TYP)
θ	1 °	7 °	1°	7 *

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